Tunable circular dipolelike system in graphene: Mixed electron-hole states

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Coupled electron-hole states are realized in a system consisting of a combination of an electrostatic potential barrier and ring-shaped potential well, which resembles a circular dipole. A perpendicular magnetic field induces confined states inside the Landau gaps which are mainly located at the barrier or ring. Hybridizations between the barrier and ring states are seen as anticrossings in the energy spectrum. As a consequence, the energy levels show an oscillating dependence on the electrostatic potential strength in combination with an oscillating migration of the wave functions between the barrier and ring. At the anticrossing points the quantum state consists of a mixture of electron and hole. The present system mimics closely the behavior of a relativistic dipole on gapped graphene.

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I. INTRODUCTION

The experimental observation of graphene [1,2] as a stable two-dimensional (2D) system together with its interesting electronic properties [3] has attracted a lot of attention. However, the gapless nature of the spectrum together with the linear spectrum has drastic consequences for the charge carriers in graphene: charge carriers cannot be confined by an electrostatic potential as shown by the Klein tunneling effect [4]. Controlling the charge carriers in graphene is, however, essential for future electronic applications of graphene.

One possibility to control the charge carriers in graphene is by confining them in quantum dots. This can be done, for example, by cutting out a finite-size flake of graphene which naturally confines the charge carriers [5–8]. However, it was shown in both theoretical and experimental studies that the nature of the edges of the finite-size flakes drastically alters the energy spectrum [8]. Since the edges are difficult to control experimentally, this poses major challenges regarding future applications.

However, in Refs. [9–11] another possibility to control the charge carriers in graphene has been demonstrated. Here it was shown that by combining an electric and magnetic field a highly tunable quantum dot can be created. The magnetic field quantizes the energy spectrum and thus creates Landau gaps between the Landau levels. Using a nonhomogeneous electrical potential, one is able to induce localized states that are inside those gaps. The high degree of tunability of this type of dot system, together with the absence of edges, makes it very promising for the use in future electronic applications of graphene (for example, in quantum information and quantum computing [12]). Furthermore, recent experiments [13–16] have demonstrated its high degree of tunability.

Coupling between quantum dot states is important to understand because of their potential use for promising applications in quantum information and optoelectronics [17], [18]. Studying the coupling between two lateral quantum dots [19] is impossible analytically due to the breaking of angular symmetry. In this paper, we consider an electrostatic potential barrier and ring (see Fig. 1) that are combined in a dipolelike configuration. By applying a perpendicular magnetic field it is possible to realize confinement in either the potential barrier and/or ring. We show that by tuning the magnetic and electric fields, electron and hole states located at either the potential ring or barrier can be coupled. This coupling is highly tunable by the external fields, which paves the way toward the experimental study of magnetoelectrostatic confined coupled graphene quantum dots. Furthermore, we show that the general behavior of the spectrum and probability densities closely mimics the behavior of a relativistic dipole, hence, our proposed system can provide a platform to study relativistic dipole physics.

By using step potentials and the circular symmetry of the system we are able to obtain formal analytical expressions for the energy spectrum and wave functions. Note that studying the interaction between two lateral quantum dots usually requires breaking angular symmetry which prevents exact analytical solutions.

The paper is structured as follows. In Sec. II we present the analytical model with expressions for the wave functions and the nonlinear equations that determine the energy spectrum. In order to understand the coupling between the circular quantum barrier and the ring-shaped well, we first consider both potential structures separately in Sec. III. The combination of a potential barrier and ring is studied in Sec IV. In Sec. V we present the main conclusions of this work.

II. ANALYTICAL MODEL

In this section we present our system and derive the equations governing this system, the energy spectrum, and wave functions.
in the presence of a perpendicular magnetic field, is given by

\[ H = v_F (p + eA) \cdot \sigma + V(r) \cdot I. \] (1)

Here, \( V(r) \) is an arbitrary radially symmetric electrostatic potential, \( \sigma \) are the Pauli matrices, and \( A = B/2(-y, x, 0) \) is the vector potential in the symmetric gauge. In this work we will consider \( V(r) \) as being a stepwise potential. The energy spectrum is determined by solving the Schrödinger equation \( H \Psi = E \Psi \). Due to the circular symmetry we have \([H, J_z] = 0\) where \( J_z = l_z + \hbar \sigma_z/2 \) is the total angular momentum. This implies that using polar coordinates, the two-component wave function has the form \( \Psi = (\phi_a, \phi_b) = e^{im\theta}(\psi_a(r), e^{i\theta}\psi_b(r)) \), where \( m = 0, \pm 1, \pm 2, \ldots \) is the total angular quantum number. Using the latter ansatz the coupled radial equations are given by

\[ \frac{V(r)}{\hbar v_F} \psi_a + \left( \frac{\partial}{\partial r} + \frac{m + 1}{r} \right) \psi_b + \frac{r}{\hbar^2 B} \psi_b = E \frac{\hbar v_F}{\hbar v_F} \psi_a, \] (2a)

\[ \left( -\frac{\partial}{\partial r} + \frac{m}{r} \right) \psi_b + V(r) \frac{\hbar v_F}{\hbar v_F} \psi_b + \frac{r}{\hbar^2 B} \psi_b = E \frac{\hbar v_F}{\hbar v_F} \psi_a. \] (2b)

Here, \( l_B = \sqrt{\hbar/eB} \) is the magnetic length and \( E \) the energy. Solving Eq. (2a) for \( \psi_a \) gives the following expression in the case of a constant potential \( V(r) = V \):

\[ \psi_a = \frac{\hbar v_F}{(E - V)} \left( \frac{\partial}{\partial r} + \frac{m + 1}{r} \right) \psi_b + \frac{\hbar v_F}{(E - V)} \frac{r}{2l_B} \psi_b. \] (3)

Substituting the latter expression in Eq. (2b) results in the uncoupled second-order differential equation

\[ \frac{\partial^2 \psi_b}{\partial r^2} + \frac{1}{r} \frac{\partial \psi_b}{\partial r} - \left[ \frac{(m + 1)^2}{r^2} + \frac{m}{l_B^2} + \frac{r^2}{4l_B^2} - \frac{(E - V)^2}{\hbar^2 v_F^2} \right] \psi_b = 0. \] (4)

This equation has two independent exact solutions given by the following closed expressions for the wave function:

\[ F_b(V, r) = 2^{-\frac{m}{2}} e^{-r^2/4l_B^2} r^{-m-1} \times \left( \frac{l_B^2}{2\hbar^2 v_F^2} (E - V)^2 - 1 - m, \frac{r^2}{2l_B^2} \right), \] (5a)

\[ G_b(V, r) = 2^{-\frac{m}{2}} e^{-r^2/2l_B^2} r^{-m-1} \times \left( -\frac{l_B^2}{2\hbar^2 v_F^2} (E - V)^2, -m, \frac{r^2}{2l_B^2} \right), \] (5b)

where \( L \) is the generalized Laguerre polynomial and \( U \) is the Tricomi confluent hypergeometric function. The solution \( F_b(V, r) \) is regular at the origin \( r = 0 \) while it is irregular at infinity. The other solution \( G_b(V, r) \) is irregular at the origin and regular at infinity.

The solutions for \( \psi_a(r) \) can be obtained by plugging the solutions (5a) and (5b) into Eq. (3) giving the following wave functions:

\[ F_a(V, r) = \frac{2^{-\frac{m}{2}} \hbar v_F}{l_B^2} e^{-r^2/4l_B^2} r^{-m} \times \left( -1 + \frac{l_B^2}{\hbar^2 v_F^2} (E - V)^2, -m, \frac{r^2}{2l_B^2} \right) \] (6a)

\[ G_a(V, r) = \frac{2^{-\frac{m}{2}} \hbar v_F}{l_B^2} e^{-r^2/2l_B^2} r^{-m} \times \left( -\frac{l_B^2}{2\hbar^2 v_F^2} (E - V)^2, -m, \frac{r^2}{2l_B^2} \right) \] (6b)
and
\[ G_d(V, r) = \frac{2e^{-\frac{2}{m}(E - V)}}{2\hbar v_F} e^{-r/|a_\ell|^m} \times U \left[ 1 - \frac{1}{r^2} (E - V)^2, 1 - m, \frac{r^2}{2|b_\ell|^2} \right]. \] (6b)

C. Wave functions

In this section we derive the wave functions for the potential barrier, potential ring, and potential dipole system.

1. Potential barrier

We consider first a circular potential barrier of radius \( a \) and height \( V_b \). Thus, only two regions are relevant: in region I (\( r < a \)) the solution is given by the wave functions
\[
\psi^I_a = A_1 F_a(V_b, r), \quad (7a)
\]
\[
\psi^I_b = A_2 F_a(V_b, r), \quad (7b)
\]
where \( A_1 \) is an integration constant. In region II (\( r > a \)) we have to take the other solution for the wave functions
\[
\psi^II_a = B_1 G_a(0, r), \quad (8a)
\]
\[
\psi^II_b = B_1 G_a(0, r), \quad (8b)
\]
where \( B_1 \) is an integration constant.

The above wave functions have to be matched at the boundary \( r = a \), which results into the following wave functions in region I:
\[
\psi^I_a = B_1 \frac{G_a(0, a)}{F_a(V_b, a)} F_a(V_b, r), \quad (9a)
\]
\[
\psi^I_b = B_1 \frac{G_a(0, a)}{F_a(V_b, r)} F_a(V_b, r). \quad (9b)
\]

In region II we have the following wave functions:
\[
\psi^II_a = B_1 G_a(0, r), \quad (10a)
\]
\[
\psi^II_b = B_1 G_a(0, r). \quad (10b)
\]

2. Potential ring

Now, we consider the situation where we have only a potential ring of depth \(-V_r\) with inner (outer) radius \( b \) (\( c \)). In this case, we have three regions. Region I is defined as \( r < b \), where the wave function is given by the expressions
\[
\psi^I_a = A_2 F_a(0, r), \quad (11a)
\]
\[
\psi^I_b = A_2 F_b(0, r). \quad (11b)
\]
Region II is defined as \( b < r < c \) where an electrostatic potential of strength \(-V_r\) is present. Now, we have to keep the two solutions of Eq. (1) and we have the following wave functions:
\[
\psi^II_a = B_2 F_a(-V_r, r) + C_2 G_a(-V_r, r), \quad (12a)
\]
\[
\psi^II_b = B_2 F_b(-V_r, r) + C_2 G_b(-V_r, r). \quad (12b)
\]

In region III, which is defined as \( r > c \), we have the following wave functions:
\[
\psi^III_a = D_2 G_a(0, r), \quad (13a)
\]
\[
\psi^III_b = D_2 G_b(0, r). \quad (13b)
\]
The wave functions have to be matched at \( r = b \) and \( c \). This leads to the wave functions given in the Appendix.

3. Circular potential dipole

In this situation we consider both a potential barrier and a ring, i.e., the combination of the previous two potential structures. In this case, we have four regions. Region I is defined as \( r < a \) with the wave functions
\[
\psi^I_a = A_3 F_a(V_b, r), \quad (14a)
\]
\[
\psi^I_b = A_3 F_b(V_b, r). \quad (14b)
\]
In region II, where \( a < r < b \), we have the following wave functions:
\[
\psi^II_a = B_3 F_a(0, r) + C_3 G_a(0, r), \quad (15a)
\]
\[
\psi^II_b = B_3 F_b(0, r) + C_3 G_b(0, r). \quad (15b)
\]
In region III, which is defined as \( b < r < c \), we have an electrostatic potential \(-V_r\), the corresponding wave functions are given by the expressions
\[
\psi^III_a = D_3 F_a(-V_r, r) + E_3 G_a(-V_r, r), \quad (16a)
\]
\[
\psi^III_b = D_3 F_b(-V_r, r) + E_3 G_b(-V_r, r). \quad (16b)
\]
Last, we have region IV which is defined as \( r > c \); in this region we have the following wave functions:
\[
\psi^IV_a = F_3 G_a(0, r), \quad (17a)
\]
\[
\psi^IV_b = F_3 G_b(0, r). \quad (17b)
\]
Matching the wave functions at the boundaries \( r = a \), \( r = b \), and \( r = c \) leads to the solutions which are given in the Appendix.

D. Energy equations

Using the wave functions derived in the previous subsection, we derive the equation for the energy spectrum.

1. Potential barrier

The energy equation can be obtained by matching the wave functions (7a) and (7b) with the wave functions (8a) and (8b) at the boundary between the two regions. This gives the following algebraic equation:
\[
\frac{F_a(V_b, a)}{F_b(V_b, a)} = \frac{G_a(0, a)}{G_b(0, a)}, \quad (18)
\]
whose solutions determine the energy spectrum.

2. Potential ring

Matching the wave functions (11a) and (11b) with the wave functions (12a) and (12b) between regions I and II gives the...
The procedure is completely analogous as for the quantum barrier and quantum ring. Matching the wave functions (14a) and (14b) with the wave functions (15a) and (15b) between regions II and III we can find the following ratio of integration constants:

\[
\frac{B_3}{C_3} = \frac{G_a(0, a)F_b(V_b, a) - G_b(0, a)F_a(V_b, a)}{F_b(0, a)F_a(V_b, a) - F_a(0, a)F_b(V_b, a)}.
\]

(23)

Matching the wave functions (16a) and (16b) with the wave functions (17a) and (17b) between regions I and IV we find the following ratio:

\[
\frac{C_3}{\xi_3} = \frac{G_b(-V_r, c)G_a(0, c) - G_a(-V_r, c)G_b(0, c)}{F_b(-V_r, c)G_a(0, c) - F_a(-V_r, c)G_b(0, c)}.
\]

(24)

Finally, matching the wave functions (15a) and (15b) with the wave functions (16a) and (16b) between regions II and III, we obtained the following equation:

\[
\frac{F_a(0, b)G_a(-V_r, b) + \frac{\xi_a}{B_3}G_b(0, b)}{F_b(0, b) + \frac{\xi_b}{B_3}G_b(0, b)} = \frac{F_a(-V_r, b) + \frac{\xi_a}{B_3}G_b(-V_r, b)}{F_b(-V_r, b) + \frac{\xi_b}{B_3}G_b(-V_r, b)},
\]

(25)

whose solutions give the energy spectrum.

### III. Numerical Results for the Decoupled Systems

In this section we will discuss the results obtained from solving the energy equations (18) and (22).

#### A. Potential barrier

We consider first the results for the simplest system consisting of just a circular quantum barrier and solve numerically the energy equation (18) for different values of the potential strength and angular quantum number. This system was investigated previously in Ref. [9], but to understand the spectrum of a dot-ring system, we repeat here the essential results.

In Fig. 1 we show the energy spectrum as function of the potential barrier strength \( V_b \) for three angular quantum number values \( m = 0, \pm 1 \) and a magnetic length \( l_B = 15 \) nm (corresponding to \( B \approx 3 \) T). We took the strength of the potential barrier \( V_b \) as function of the potential barrier strength for three values of the angular momentum quantum number \( m = 0 \) (blue curves), \( m = -1 \) (green curves), and \( m = 1 \) (red curves) and in the presence of a perpendicular magnetic field of \( B \approx 3 \) T corresponding to a magnetic length \( l_B = 15 \) nm.

![Energy spectrum plot](image-url)

**Fig. 2.** Energy spectrum of a circular potential barrier of radius \( a = 10 \) nm as function of the potential barrier strength for three values of the angular momentum quantum number \( m = 0 \) (blue curves), \( m = -1 \) (green curves), and \( m = 1 \) (red curves) and in the presence of a perpendicular magnetic field of \( B \approx 3 \) T corresponding to a magnetic length \( l_B = 15 \) nm.
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FIG. 3. Probability density shown for the points marked in Fig. 2. The position of the potential barrier is marked by the colored surface under the density profile. The left side panels correspond to the density of states inside the Landau gap, while the right panels correspond to states outside the Landau gap.

anticrosses with the corresponding electron level. This behavior reminds of the supercritical instability effect in gapped graphene where bound states in the gap are allowed to enter the corresponding continuum [20–22], with the important difference that in that case the effect is created by a Coulomb impurity and not a potential barrier. The fact that a potential of arbitrary shape could be used to create supercritical states was shown explicitly in Refs. [23,24].

In order to show the difference in behavior for the states inside the Landau gap as compared to those outside it, we show in Fig. 3 the probability densities for the points marked in Fig. 2. The location of the barrier is shown as a colored area under the probability density plots. From these figures it is clear that the states inside the Landau gap (left figures in Fig. 3) are more localized inside the potential barrier and form true quantum dot states. States outside the gap region are weakly localized in the potential barrier and these states exhibit more a Landau-level-like behavior. Interestingly for the states located in the gap region, we find that the $m = -1$ state (green curve) is much less localized in the barrier as compared to the $m = 0$ (blue curve) and $m = 1$ (red curve) state. This explains the smoother dependence of the energy, compared to the $m = 1$ states, as a function of the barrier strength.

B. Potential ring

Now, we consider an electrostatic potential ring and investigate the corresponding energy spectrum. In the presence of a perpendicular magnetic field it is possible to create quantum dot states located in the circular quantum ring within the Landau gaps. We emphasize the differences between quantum dot states located at the barrier compared to those located at a ring-shaped potential. While graphene quantum rings cut out from graphene sheets have been extensively studied both within tight-binding and continuum models [25–27], the system discussed in this paper, the combination of a ring-shaped potential and magnetic field, has not been studied in the literature to date.

In Fig. 4 we show the spectrum of an electrostatic quantum well ring for the same three angular quantum numbers as shown in Fig. 2 for the potential barrier. For the ring the size parameters are $b = 30 \text{ nm}$ and $c = 35 \text{ nm}$.

FIG. 4. Energy spectrum of a ring potential as function of the depth of the potential well for three values of the angular momentum quantum number $m = 0$ (blue curves), $m = -1$ (green curves), and $m = 1$ (red curves) with inner (outer) radius $b = 30 \text{ nm}$ ($c = 35 \text{ nm}$). A perpendicular magnetic field is applied with strength $B \approx 3 \text{ T}$ which results in $l_B = 15 \text{ nm}$. 
In contrast with the potential barrier, no hole states enter the gap region but electron states enter instead. This is merely a consequence of the fact that we took a potential well ring instead of a barrier. Remember that the spectrum has electron-hole symmetry in the sense that the spectrum is invariant under the transformations $E \rightarrow -E$ and $V_r \rightarrow -V_r$, effectively changing electron states into hole ones. With increasing potential strength, electron states are allowed to sink into the Landau gaps where they exhibit almost a linear dependence on the potential strength. This behavior continues until the electron level touches the first hole level at negative energy and an anticrossing occurs, similar to the above quantum barrier results.

In Fig. 5 the probability density is shown for the points (1)–(6) marked in Fig. 4. The area with the potential ring is indicated by the colored surface under the density profile. The left side panels correspond to the probability density of states inside the Landau gap, while right panels correspond to the states outside the Landau gap.

![Probability density for points (1)–(6)](image)

FIG. 5. Probability density shown for the points (1)–(6) marked in Fig. 4. The area with the potential ring is indicated by the colored surface under the density profile. The left side panels correspond to the probability density of states inside the Landau gap, while right panels correspond to the states outside the Landau gap.

In general, for all three states the densities exhibit similar behavior. However, the number of peaks inside the electrostatic ring increases with the number of states entering the gap region. The first state has one peak, the second two, and the third three. This behavior reminds of the increasing number of nodes with increasing principal quantum number in the case of a relativistic hydrogen atom. Interestingly, the behavior outside the quantum ring is almost exactly the same for the three successive states, and these states are only distinguished by the behavior inside the quantum ring.

IV. CIRCULAR POTENTIAL DIPOLE

Here, we investigate the interaction between the single-electron energy spectrum of a combined quantum barrier and ring-shaped well. By combining a barrier and ring with opposite sign for electrostatic potential strength, it is possible to couple electron and hole states which show up as anticrossings. This coupling can be effectively tuned by the strength of the applied electrostatic and magnetic fields.
In Fig. 7 we show the spectrum as function of the electrostatic potential strength for three values of the angular momentum quantum number $m = 0$ (blue curves), $m = -1$ (green curves), and $m = 1$ (red curves). The size of the dipole system we took $a = 10$ nm, $b = 30$ nm, and $c = 35$ nm and the magnetic field value is $l_B \approx 3$ T corresponding to $l_B = 15$ nm.

In Fig. 7, the localization shifts from the barrier to the ring and is equally distributed at the point of anticrossing. However, quantitatively, before and after the point of anticrossing the probability density is more spread out over the barrier and ring as compared to the densities shown in Fig. 8.

Interestingly, the behavior shown in this paper, i.e., the oscillations of the energy spectrum as a function of the electrostatic potential strength and relocalization of the wave function when passing the anticrossing, are also observed in the spectrum of a relativistic dipole on gapped graphene [29–32]. Thus, the coupled quantum barrier and ring system in a magnetic field imitates relativistic dipole physics in gapped graphene. Both systems share some similarities: the magnetic...
field creates a gap in the spectrum while the electrostatic barrier and ring which are equal in strength but opposite in sign replicate a positively and negatively charged Coulomb impurity. However, experimentally the system presented in this paper has several advantages as compared to the dipole system in gapped graphene. First, the present system has many more tuning possibilities as compared to the dipole system, hence increasing the chance of detecting the rich physics of a dipole. The governing length scales can be effectively tuned by the magnetic field while the strength of the electrostatic potentials. Finally, our model has the big advantage that analytical results for the energy equations and wave functions can be obtained, the energy equations provided in this paper can be straightforwardly solved using standard root-solving methods. However, one should always consider a tradeoff between simplicity of the model and experimental relevance. In this paper we consider step potentials which in experiments can be approximately realized by an STM tip, or by local doping, or by nanostructured gates. In real experiments, the potentials produced in this way will deviate from these step potentials. However, a previous publication [9] has shown that the use of step potentials makes sense and that they provide a good approximation for the potentials present in real systems.

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APPENDIX: WAVE FUNCTIONS

In this Appendix we provide the exact form of the wave functions obtained from our analytical model.

1. Potential ring

In region I we have the wave functions

$$\psi^I_a = A_2 F_a(0, r),$$

$$\psi^I_b = A_2 F_b(0, r).$$

In region II we have the wave functions

$$\psi^{II}_a = A_2 \cdot \mathcal{B}[A F_a(-V_r, r) + G_a(-V_r, r)].$$

$$\psi^{II}_b = A_2 \cdot \mathcal{B}[A F_b(-V_r, r) + G_b(-V_r, r)].$$

Here, \( \mathcal{A} \) is defined as

$$\mathcal{A} = \frac{G_a(-V_r, c)G_b(0, c) - G_b(-V_r, c)G_a(0, c)}{F_b(-V_r, c)G_b(0, c) - F_a(-V_r, c)G_b(0, c)},$$

and \( \mathcal{B} \) is defined as

$$\mathcal{B} = \frac{F_a(0, b)}{A F_a(-V_r, b) + G_a(-V_r, b)}.$$

In region III we have the following wave functions:

$$\psi^{III}_a = A_2 C G_a(0, r),$$

$$\psi^{III}_b = A_2 C G_b(0, r).$$
Here, $C$ is given by the following expression:

$$C = \frac{E[AF_a(-V_r, c) + G_a(-V_r, c)]}{G_a(0, c)}.$$  \hspace{1cm} (A9)

2. Circular potential dipole

In region I we have the wave functions

$$\psi_a^I = A3F_a(V_b, r),$$  \hspace{1cm} (A10)

$$\psi_b^I = A3F_b(V_b, r).$$  \hspace{1cm} (A11)

In region II we have the wave functions

$$\psi_a^II = A3F[D_F(0, r) + G_a(0, r)],$$  \hspace{1cm} (A12)

$$\psi_b^II = A3F[D_F(0, r) + G_b(0, r)].$$  \hspace{1cm} (A13)

Here, $D$ and $F$ are, respectively, given by the expression

$$D = \frac{G_a(0, a)F_a(V_b, a) - G_b(0, a)F_a(V_b, a)}{F_a(0, a)F_a(V_b, a) - F_b(0, a)F_b(V_b, a)},$$  \hspace{1cm} (A14)

and

$$F = \frac{F_a(V_b, a)}{D_F(0, a) + G_a(0, a)}.$$  \hspace{1cm} (A15)

In region III we have the following wave functions:

$$\psi_a^III = A3G[E_F(-V_r, r) + G_a(-V_r, r)],$$  \hspace{1cm} (A16)

$$\psi_b^III = A3G[E_F(-V_r, r) + G_b(-V_r, r)].$$  \hspace{1cm} (A17)

Here, $E$ and $G$ are, respectively, given by the expressions

$$E = \frac{G_a(-V_r, c)G_b(0, c) - G_b(-V_r, c)G_a(0, c)}{F_b(-V_r, c)G_a(0, c) - F_a(-V_r, c)G_b(0, c)}$$  \hspace{1cm} (A18)

and

$$G = \frac{D_F(0, b) + G_a(0, b)}{E_F(-V_r, b) + G_a(-V_r, b)}.$$  \hspace{1cm} (A19)

In region IV we have the wave functions

$$\psi_a^IV = A3H[G_a(0, r),$$  \hspace{1cm} (A20)

$$\psi_b^IV = A3H[G_b(0, r).$$  \hspace{1cm} (A21)

Here, $H$ is given by the expression

$$H = \frac{G[E_F(-V_r, c) + G_a(-V_r, c) + G_b(-V_r, c)]}{G_a(0, c)}.$$  \hspace{1cm} (A22)


